

# **RJH1CV6DPQ-E0**

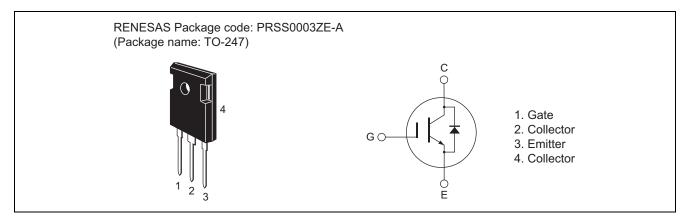
1200V - 30A - IGBT Application: Inverter

R07DS0524EJ0700 Rev.7.00 Jun 13, 2013

#### **Features**

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.8 \text{ V}$  typ. (at  $I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}, Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 180 \text{ ns typ.}$ ) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f$  = 120 ns typ. (at  $V_{CC}$  = 600 V,  $V_{GE}$  = 15 V,  $I_C$  = 30 A, Rg = 5  $\Omega$ , Ta = 25°C, inductive load)

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	1200	V
Gate to emitter voltage		$V_{GES}$	±30	V
Collector current	Tc = 25°C	Ic	60	А
	Tc = 100°C	Ic	30	А
Collector peak current		ic(peak) Note1	90	А
Collector to emitter diode forward current		I <sub>DF</sub>	30	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	90	А
Collector dissipation		P <sub>C</sub> Note2	290	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.43	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

 $di_F/dt = 100 A/\mu s$ 

 $\mu \text{C}$ 

Α

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> /I <sub>R</sub>	_	_	5	μΑ	V <sub>CE</sub> = 1200 V, V <sub>GE</sub> = 0	
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	_	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	2.3	V	$I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	$V_{CE(sat)}$	_	2.6	_	V	$I_C = 60 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1600	_	pF	V <sub>CE</sub> = 25 V	
Output capacitance	Coes	_	85	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	43	_	pF	f = 1 MHz	
Total gate charge	Qg	_	105	_	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V	
Gate to emitter charge	Qge	_	14	_	nC		
Gate to collector charge	Qgc	_	55	_	nC	I <sub>C</sub> = 30 A	
Turn-on delay time	t <sub>d(on)</sub>	_	46	_	ns	$V_{CC} = 600 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 30 \text{ A}$ $Rg = 5 \Omega$ Inductive load	
Rise time	t <sub>r</sub>	_	33	_	ns		
Turn-off delay time	t <sub>d(off)</sub>	_	125	_	ns		
Fall time	t <sub>f</sub>	_	120	_	ns		
Turn-on energy	Eon	_	2.3	_	mJ		
Turn-off energy	E <sub>off</sub>	_	1.7	_	mJ		
Total switching energy	E <sub>total</sub>	_	4.0	_	mJ		
Short circuit withstand time	t <sub>sc</sub>	_	5	_	μs	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$	
						Tc ≤ 125°C	
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FRD forward voltage	$V_{F}$	_	2.0		V	$I_F = 30 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t <sub>rr</sub>	_	180	_	ns	I <sub>F</sub> = 30 A	

0.63

9.2

 $\mathsf{Q}_{\mathsf{rr}}$ 

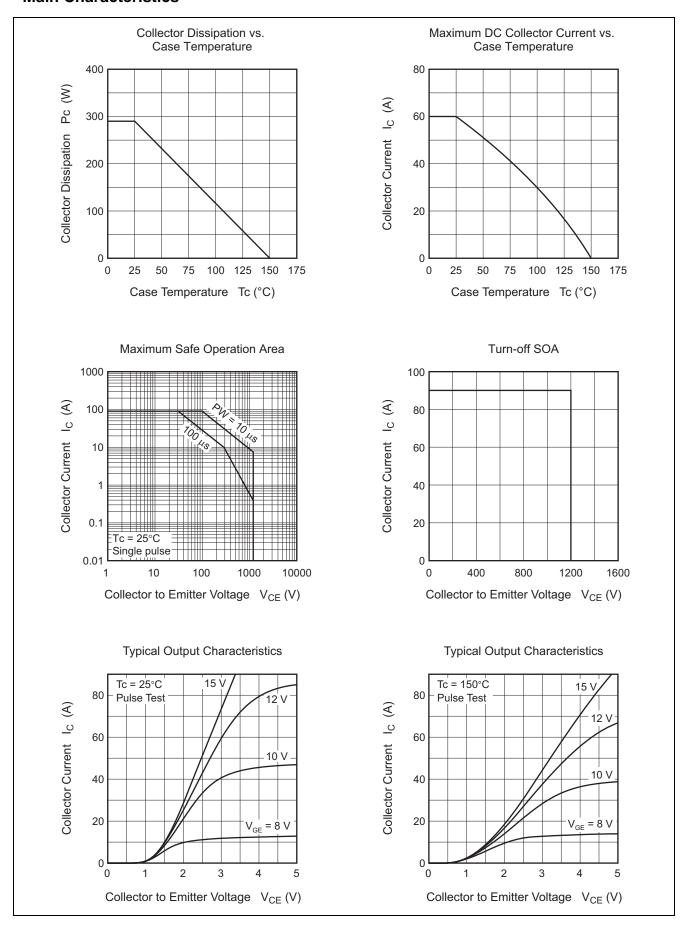
 $I_{rr}$ 

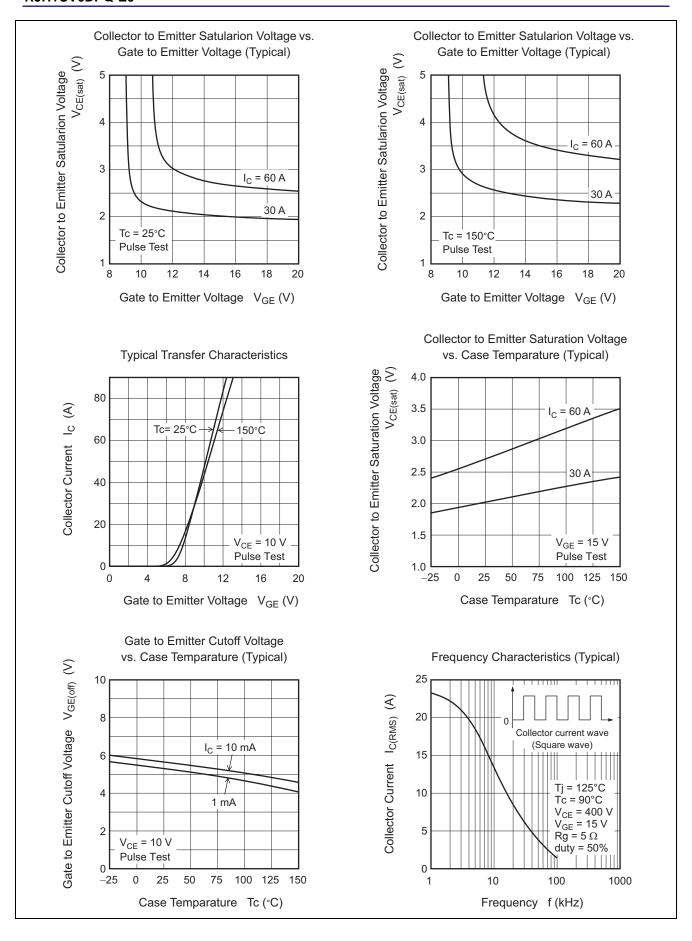
Notes: 3. Pulse test.

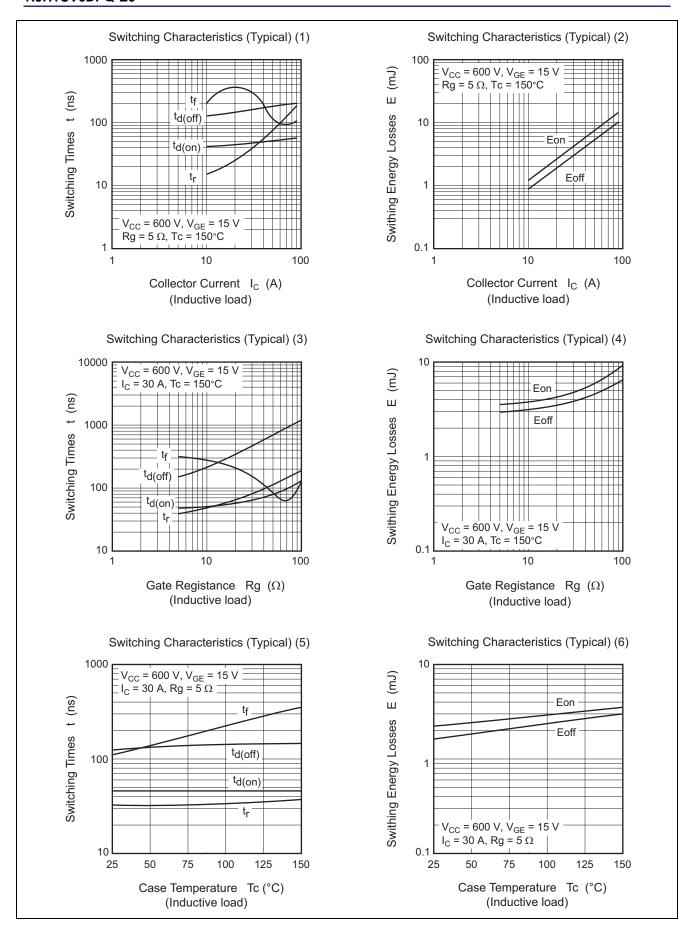
FRD reverse recovery charge

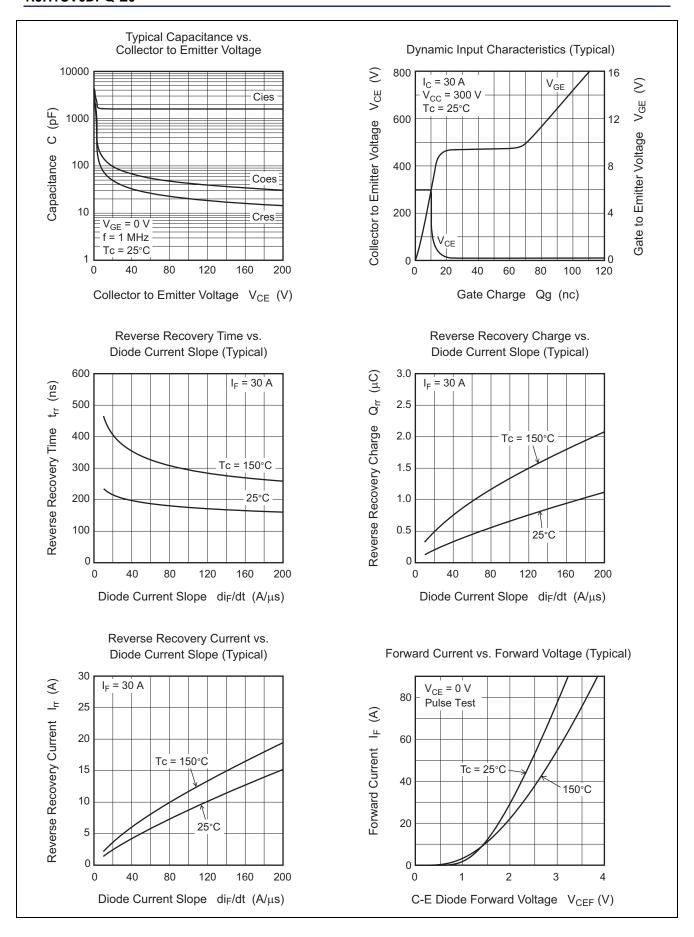
FRD peak reverse recovery current

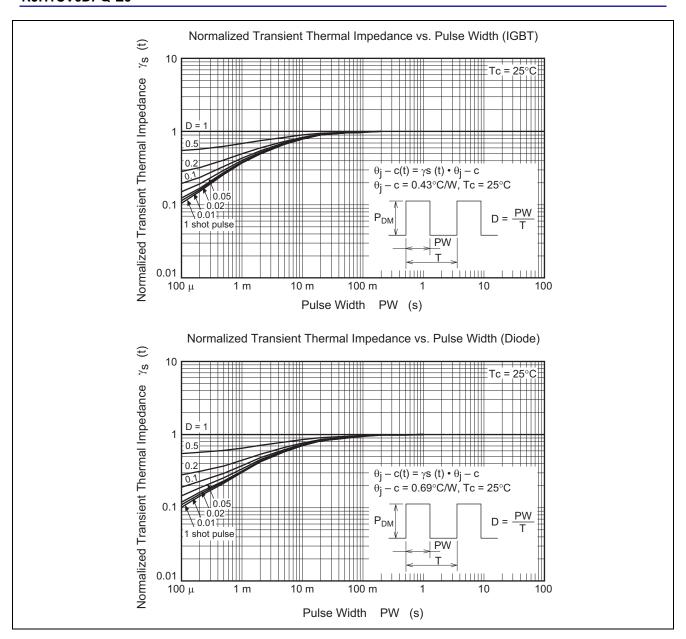
## **Main Characteristics**

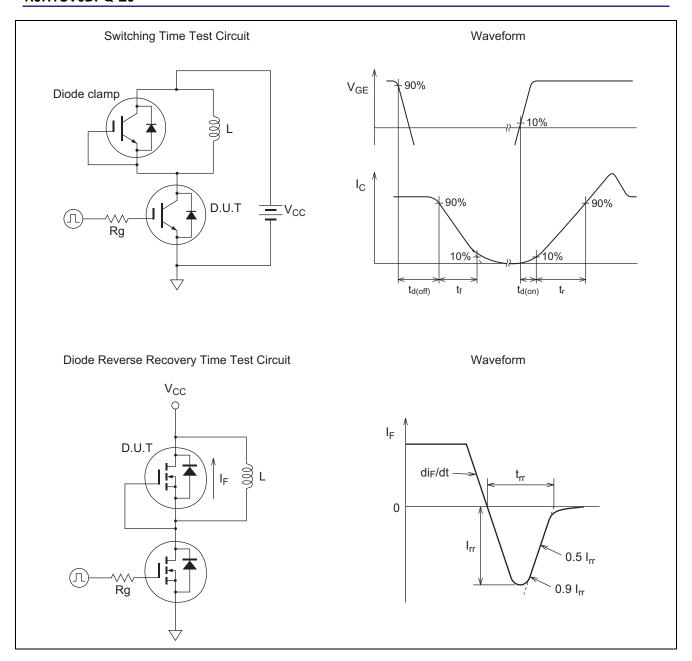




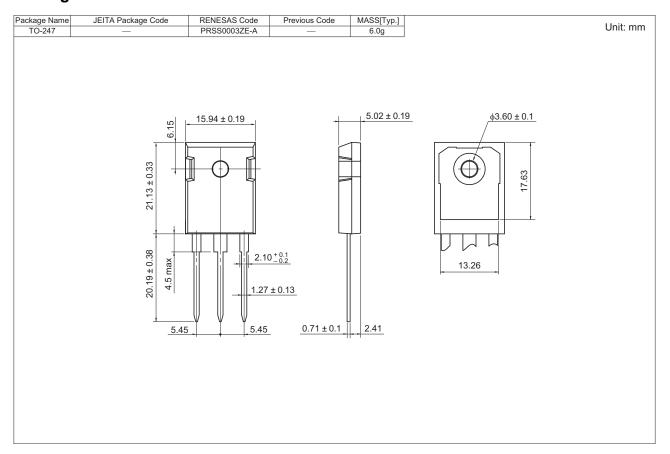








## **Package Dimension**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container	
RJH1CV6DPQ-E0#T2	450 pcs	Tube	

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